

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (MACH II π -MOS V)

TPCA8009-H

High Speed Switching Applications
 Switching Regulator Applications
 DC/DC Converter Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: $Q_{sw} = 3.7 \text{ nC (typ.)}$
- Low drain-source ON-resistance: $R_{DS(ON)} = 0.23\Omega \text{ (typ.)}$
- High forward transfer admittance: $|Y_{fs}| = 4.5\text{S (typ.)}$
- Low leakage current: $I_{DSS} = 100 \mu\text{A (max)}$ ($V_{DS} = 150 \text{ V}$)
- Enhancement mode: $V_{th} = 2.0 \text{ to } 4.0 \text{ V}$ ($V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$)

Absolute Maximum Ratings (Ta = 25°C)

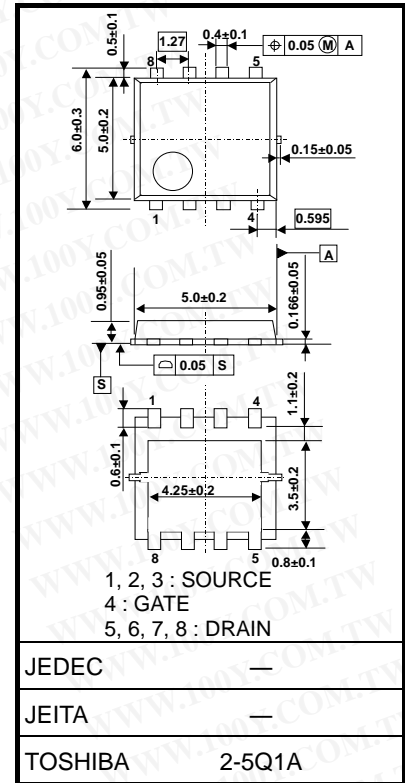
Characteristic		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	150	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	150	V
Gate-source voltage		V_{GSS}	± 20	V
Drain current	DC (Note 1)	I_D	7	A
	Pulsed (Note 1)	I_{DP}	14	
Drain power dissipation	($T_c=25^\circ\text{C}$)	P_D	45	W
Drain power dissipation	($t = 10 \text{ s}$) (Note 2a)	P_D	2.8	W
Drain power dissipation	($t = 10 \text{ s}$) (Note 2b)	P_D	1.6	W
Single-pulse avalanche energy	(Note 3)	E_{AS}	34	mJ
Avalanche current		I_{AR}	7	A
Repetitive avalanche energy	($T_c=25^\circ\text{C}$) (Note 4)	E_{AR}	1.5	mJ
Channel temperature		T_{ch}	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$

Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

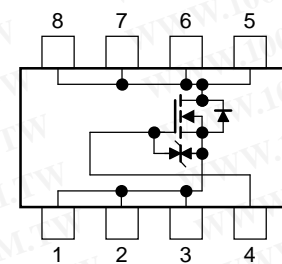
This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm



Weight: 0.068 g (typ.)

Circuit Configuration

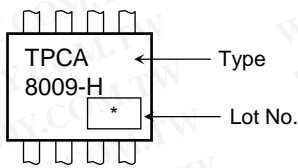


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Thermal Characteristics

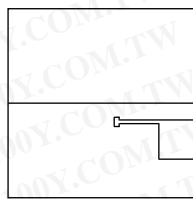
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case ($T_c=25^\circ\text{C}$)	$R_{th}(ch-c)$	2.78	$^\circ\text{C/W}$
Thermal resistance, channel to ambient ($t = 10\text{ s}$) (Note 2a)	$R_{th}(ch-a)$	44.6	$^\circ\text{C/W}$
Thermal resistance, channel to ambient ($t = 10\text{ s}$) (Note 2b)	$R_{th}(ch-a)$	78.1	$^\circ\text{C/W}$

Marking (Note 5)

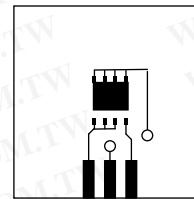


Note 1: The channel temperature should not exceed 150°C during use.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



(a)



(b)

Note 3: $V_{DD} = 50\text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 1\text{ mH}$, $R_G = 25\ \Omega$, $I_{AR} = 7\text{ A}$

Note 4: Repetitive rating: pulse width limited by max channel temperature

Note 5: * Weekly code: (Three digits)



Week of manufacture

(01 for first week of year, continuing up to 52 or 53)

Year of manufacture

(The last digit of the calendar year)

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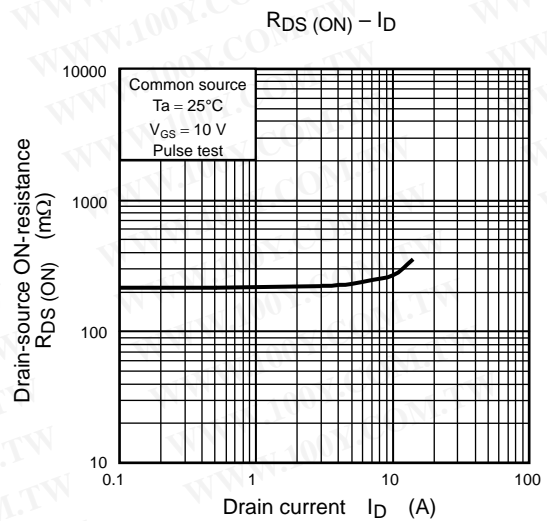
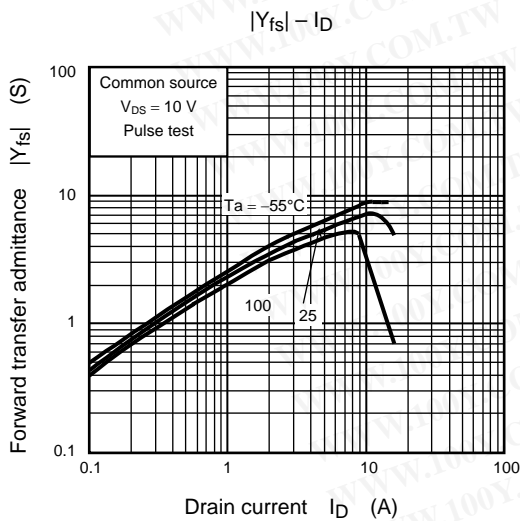
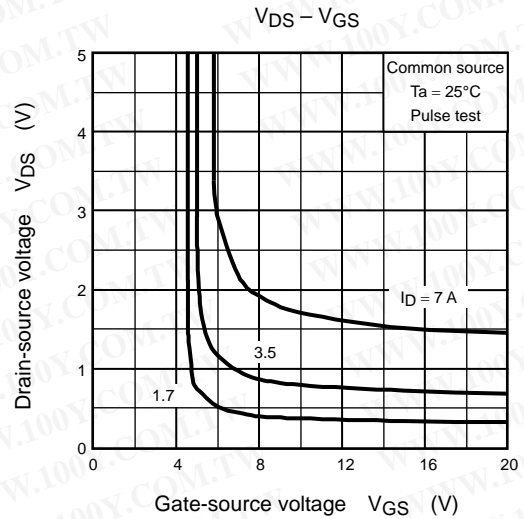
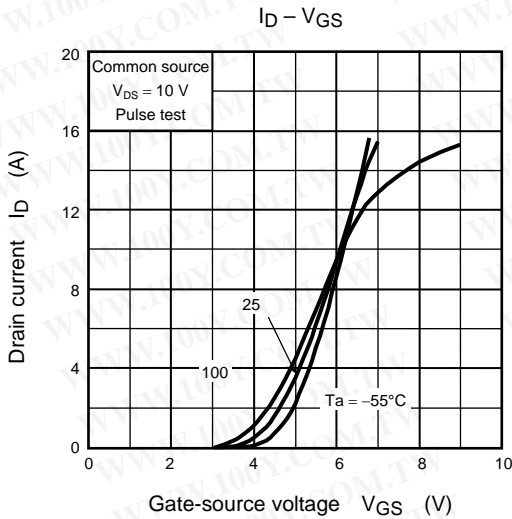
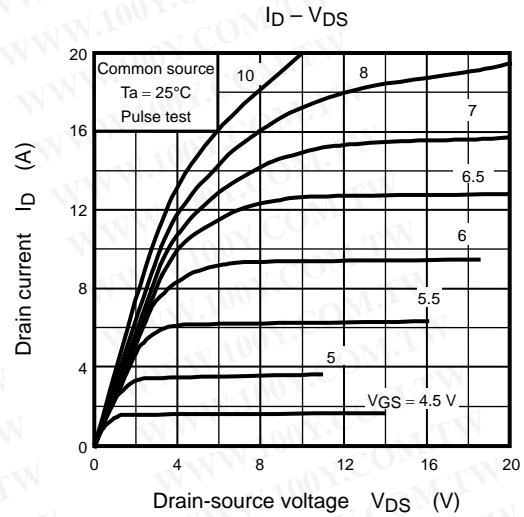
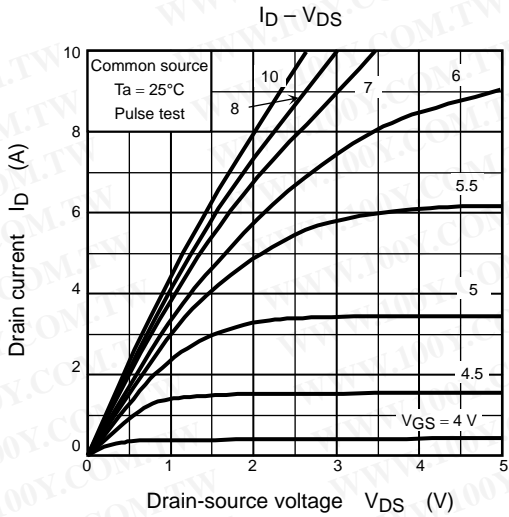
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 10	μA
Drain cutoff current		I_{DSS}	$V_{DS} = 150\text{ V}, V_{GS} = 0\text{ V}$	—	—	100	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	150	—	—	V
		$V_{(BR)DSX}$	$I_D = 10\text{ mA}, V_{GS} = -5\text{ V}$	150	—	—	
			$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	100	—	—	
Gate threshold voltage		V_{th}	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	2.0	—	4.0	V
Drain-source ON-resistance		$R_{DS(ON)}$	$V_{GS} = 10\text{ V}, I_D = 3.5\text{ A}$	—	0.23	0.35	Ω
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 3.5\text{ A}$	2.1	4.5	—	S
Input capacitance		C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	600	—	pF
Reverse transfer capacitance		C_{rss}		—	20	—	
Output capacitance		C_{oss}		—	220	—	
Switching time	Rise time	t_r	<p>$V_{GS} = 10\text{ V}, 0\text{ V}$ $I_D = 3.5\text{ A}$ $R_L = 21\ \Omega$ $V_{DD} \approx 75\text{ V}$ Duty $\leq 1\%$, $t_w = 10\ \mu\text{s}$</p>	—	8	—	ns
	Turn-ON time	t_{on}		—	17	—	
	Fall time	t_f		—	13	—	
	Turn-OFF time	t_{off}		—	70	—	
Total gate charge (gate-source plus gate-drain)		Q_g	$V_{DD} \approx 120\text{ V}, V_{GS} = 10\text{ V}, I_D = 7\text{ A}$	—	10	—	nC
Gate-source charge		Q_{gs}		—	7.6	—	
Gate-drain ("miller") charge		Q_{gd}		—	2.4	—	
Gate switch charge		Q_{sw}		—	3.7	—	

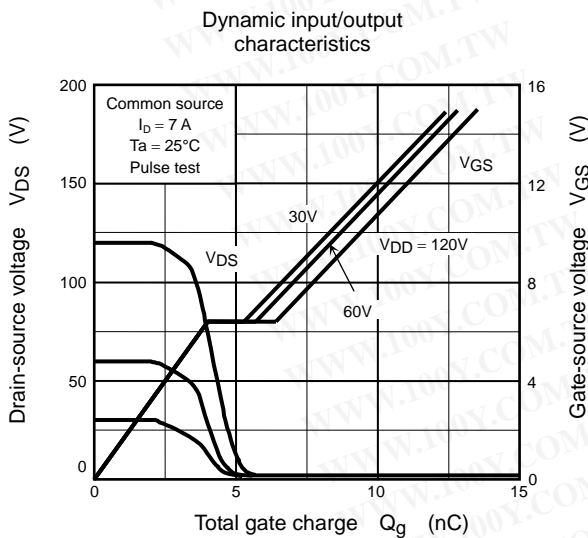
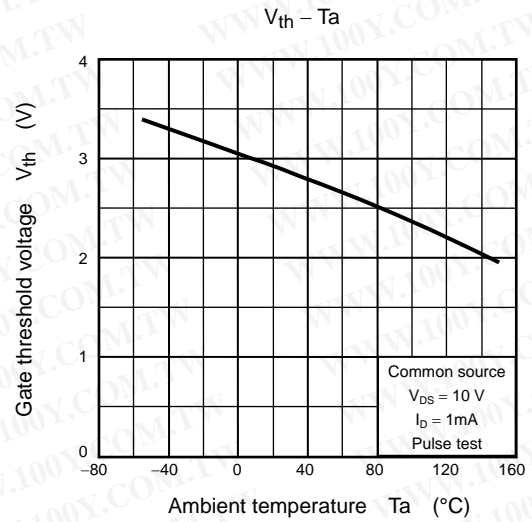
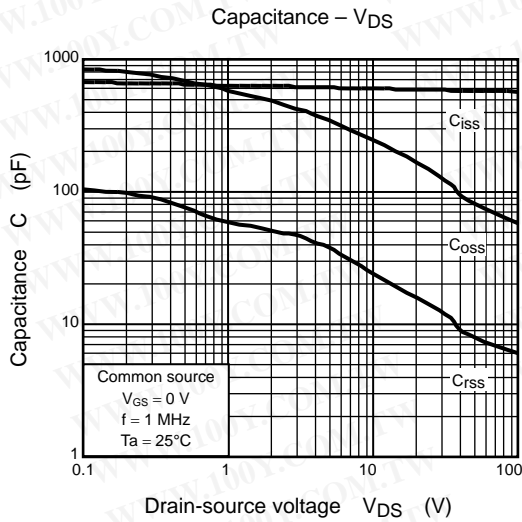
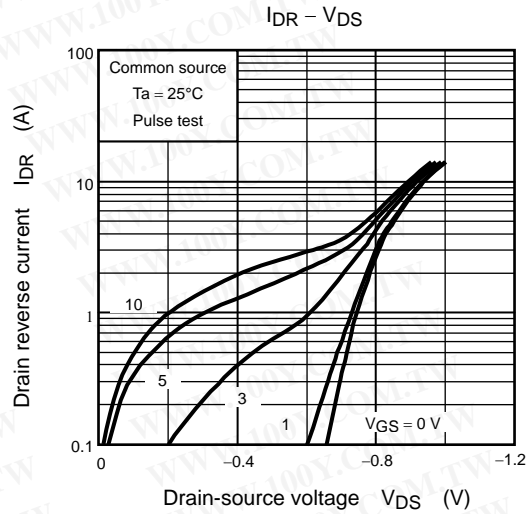
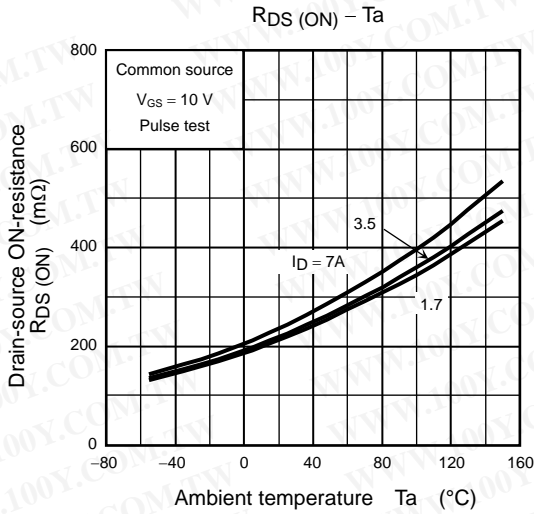
Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current	Pulse (Note 1)	I_{DRP}	—	—	—	14	A
Forward voltage (diode)		V_{DSF}	$I_{DR} = 7\text{ A}, V_{GS} = 0\text{ V}$	—	—	-2.0	V

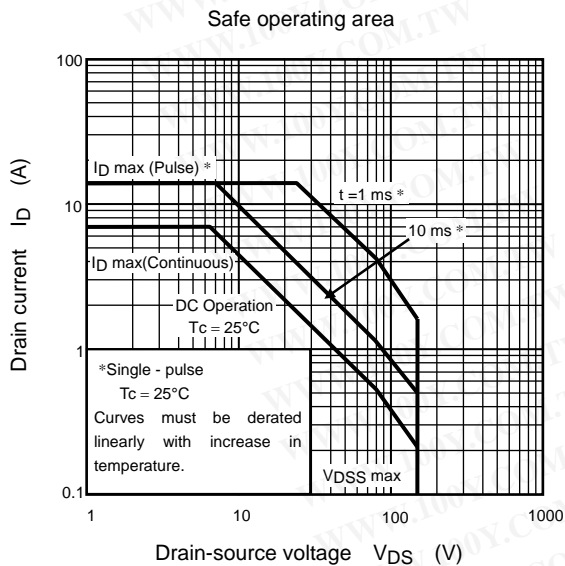
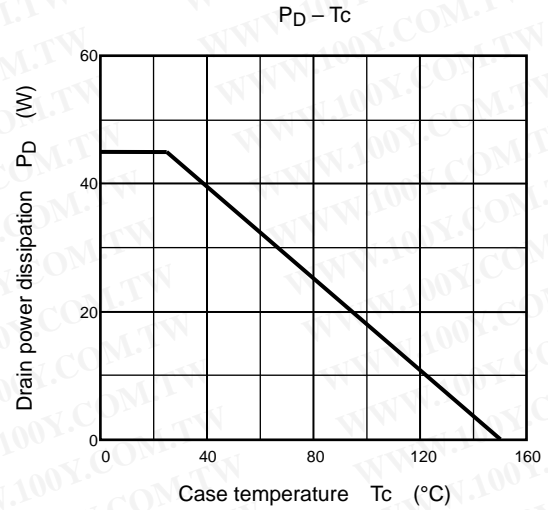
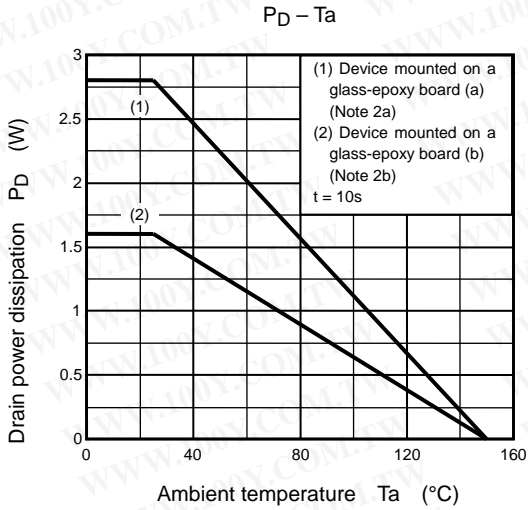
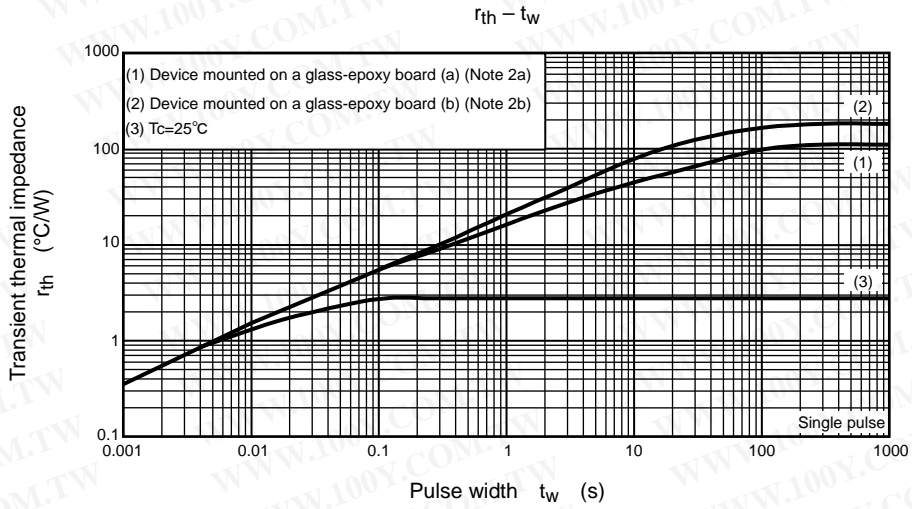
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